Doped carbon nanotubes as a model system of biased graphene

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(Received 21 October 2016; revised manuscript received 19 May 2017; published 15 August 2017)

Albeit difficult to access experimentally, the density of states (DOS) is a key parameter in solid-state systems, which governs several important phenomena including transport, magnetism, thermal, and thermoelectric properties. We study DOS in an ensemble of potassium intercalated single-wall carbon nanotubes and show, using electron spin resonance spectroscopy, that a sizable number of electron states are present, which gives rise to a Fermi-liquid behavior in this material. A comparison between theoretical and the experimental DOS indicates that it does not display significant correlation effects, even though the pristine nanotube material shows a Luttinger-liquid behavior. We argue that the carbon nanotube ensemble essentially maps out the whole Brillouin zone of graphene, thus it acts as a model system of biased graphene.

DOI: 10.1103/PhysRevB.96.075133

I. INTRODUCTION

There is a compelling link and similarity between the physical and chemical properties of the two carbon allotropes, graphene [1] and single-wall carbon nanotubes [2,3]. Both contain carbon in a nearly sp^2 configuration and both consist essentially of a surface only. Concerning electronic properties, a linear energy dispersion is present for both materials but the differing dimensionality results in different energy dependence of the electronic density of states: for graphene, it is a smooth linear function of the energy [4], whereas for single-wall carbon nanotubes (SWCNTs), it contains Van Hove singularities [5,6] whose presence is a fingerprint of the one-dimensional electronic character of SWCNTs. The similarity is even more striking for graphene nanoribbons (GNRs) [7] and SWCNTs [5,6]: the electron confinement within the nanoribbon also gives rise to quantized states in a very similar manner to that of the SWCNTs. However, the quantization also means that SWCNTs and GNRs only map part of the graphene Brillouin zone since only a subset of the graphene k points are allowed for the two former materials.

In general, charge doping of graphite-based nanocarbon [8] provides a way to yield insight into the electronic and vibrational properties as a function of the chemical potential (which is measured with respect to the charge neutral state). For example, for graphite, a highly charge-doped (or stage I) phase has the KC₈ stoichiometry for potassium doping, which involves a Fermi level shift of 1.35 eV (Ref. [9]). Compelling examples in graphene and SWCNTs, when charge doping led to interesting insights, include the emergence of intraband transitions in graphene [10], the bleaching of resonance Raman

enhancement in SWCNTs [11,12], and the Luttinger to Fermiliquid crossover in SWCNTs [13].

The electronic density of states, or DOS, is the central parameter for condensed-matter systems [14]: it enters into most measurable properties such as, e.g., electric or heat transport and it governs strongly correlated phenomena such as, e.g., the superconducting transition [15]. A comparison of experimental and calculated DOS values usually provides an elaborate way to test the accuracy of the theoretical description and whether strong correlation effects play a role.

Despite its importance, DOS is hardly accessible by direct means. Energy-dependent DOS is measurable using photoemission and tunneling spectroscopy [14,16], however, both methods yield relative DOS values and the absolute value is accessible only upon extensive calibration. The value of the DOS at the Fermi level, $DOS(E_F)$, is measurable by nuclear magnetic resonance spectroscopy [17] and it proved to be an accurate method to, e.g., discover coherence effects in BCS superconductors [18] and the presence of the pseudogap in high- T_c materials [19]. For SWCNTs, NMR allowed the detection of the Luttinger-liquid state for an unprecedented temperature span [20].

The electronic specific heat and the Pauli spin susceptibility of the conduction electrons provide a direct measurement of the DOS in the absence of strong correlation effects [14]. The Pauli spin susceptibility is measurable by conduction electron spin resonance (CESR) experiments. CESR measures specifically the contribution of conduction electrons to magnetism [21], and it was successful in, e.g., identifying strong correlation effects [22] and the low-dimensional metallic character in fulleride conductors [23].

The following open questions called for a study of DOS in charge-doped SWCNTs: (i) it is still debated whether strong correlation effects are present in chemically doped SWCNTs; (ii) it is also not known to what extent the SWCNT system can be used as a model system of biased graphene given the different dimensionality of their Fermi surfaces. Herein, we present conduction electron spin resonance studies on ensembles of SWCNTs with a well-defined diameter distribution under potassium doping to induce charge transfer to the tubes. We determine the DOS from the measurement of the Pauli spin susceptibility of the conduction electrons and we compare this value with that obtained from tight-binding calculations. We find a good agreement between the two data, which confirms that an ensemble of chemically doped SWCNTs behaves as a Fermi liquid with no substantial correlation effects. We show that the large number of different SWCNT geometries that are present in our sample give rise to a homogeneous mapping of almost *all k* points in the Brillouin zone of graphene.

II. EXPERIMENTS AND CALCULATIONS

We used commercial SWCNTs prepared by the arcdischarge method from the same batch that we used previously for Raman measurements [24], peapod filling [25], and NMR studies [26]. According to Raman spectroscopy, the diameter distribution in the SWCNT samples is a Gaussian with a mean diameter of d = 1.4 nm and variance of $\sigma = 0.1$ nm. The material was purified with repeated air oxidation and acid treatments. In order to enable penetration of microwaves, thoroughly ground fine powder samples were prepared. Samples of about 5 mg were vacuum annealed at 500 °C for 1 h in an electron spin resonance (ESR) sample tube and inserted into an Ar-filled glovebox without air exposure. We note that the present samples are different from those which were used previously in NMR studies in Ref. [20]: samples in the latter work were based on nonmagnetic catalysts, prepared with a laser-ablation method, and contained ¹³C-enriched carbon. However, a thorough Raman spectroscopic and electron microscopic characterization ensured that the underlying SWCNT content and physical properties were identical.

We used two methods for the intercalation with potassium: the more conventional vapor technique [8] and intercalation in liquid ammonia [27]. The vapor method involves sealing of the SWCNTs together with an abundant amount of potassium inside a quartz tube and an annealing to 200 °C. This method works well for intercalating graphite and the surface of SWCNT samples but we found (as discussed below) that intercalation in ammonia is more efficient. Alkali metals are known to dissolve well in liquid ammonia, which was used to synthesize alkali-metal-doped fullerides [28,29], carbon nanotubes [30], or graphene oxide [31].

The saturated stoichiometry for K doping is around K : C = 1: 7 for SWCNTs [32], which is close to the KC₈ stoichiometry for graphite [8]. To ensure saturation, an about 30% higher, nonstoichiometric amount of potassium was introduced into the ESR quartz tube that was subsequently placed under ammonia atmosphere. The quartz tube was inserted into an ethanol bath that was cooled down by liquid nitrogen. The doping hence proceeds at $-60 \,^\circ$ C in liquid ammonia promoted by slight sonication. The residual ammonia is evaporated by annealing at 200 $^\circ$ C for 15 min. The as-prepared material is inserted into a new, clean ESR quartz tube.

ESR measurements were performed using a commercial *X*-band spectrometer. *g* factors were calibrated with respect to Mn^{2+} :MgO (the Mn^{2+} content of MgO is 1.5 ppm, and *g* factor is g = 2.0014 [33]) by taking into account the hyperfine interaction of Mn^{2+} to second order. The ESR intensity was calibrated with CuSO₄ · 5H₂O reference samples; the ESR intensity of each signal component is determined by fitting (derivative) Lorentzian and Dysonian curves, as is customary in the ESR literature. Raman spectrometer at 2.54 eV (488 nm). Care was taken to avoid laser-induced deintercalation of the samples; the power was thus limited to 0.5 mW. The spectral resolution was 2 cm⁻¹.

We also performed microwave impedance measurements as a function of temperature with the so-called cavity perturbation method [34,35]. This method yields the temperaturedependent resistivity (in relative units), which is otherwise unavailable for air-sensitive powder samples. The same samples were used for all studies.

The DOS was calculated in the nearest-neighbor tight-binding approximation for a large number (81) of (n,m) SWCNT chiralities as a function of the chemical potential [5,36]. These data were then weighted with the abundance of each tube, which was assumed to follow a Gaussian with the above mean diameter and variance [37–44]. Additional quasiparticle broadening of the Van Hove singularities of the SWCNTs due to finite lifetime effects were considered [45]. The data for an (n,m) SWCNT chirality appears along the so-called cutting lines due to the *k*-space quantization, which corresponds to the circumference of the SWCNT [5,36]. A smearing of the cutting lines due to the uncertainty principle was also included by broadening the cutting lines with a Gaussian function.

III. RESULTS AND DISCUSSION

In Fig. 1, we show the G-mode range Raman spectra of pristine, intermediate-doped, and fully potassium-doped SWCNTs. The intermediate doping was achieved by the vapor phase method, whereas the full doping was performed by the liquid ammonia method. Characteristic changes are observed in the Raman spectra of the SWCNTs upon doping: the Gmode component with lower Raman shift (known as G^- mode) broadens rapidly and vanishes [46]. The G mode component with the higher Raman shift (known as the G^+ mode) upshifts for the intermediate doping and significantly downshifts for the highest level of doping. Both observations agree well with the results of Raman studies on in situ K- and Cs-doped SWCNTs in Ref. [47], which proves that a saturated K intercalation is achieved in our samples for the liquid ammonia procedure. We find that the vapor doping does not produce homogeneously high doping levels for our relatively large sample amounts in contrast to doping thin sample films in the previous in situ Raman study [47]. A previous study [48] employed electrochemical doping on SWCNT buckypapers. The spin susceptibility found therein (as discussed below) is a factor seven times smaller than the present results, which proves the high level of doping herein.

In Fig. 2, we show the ESR spectra for the pristine and sample doped to saturation with potassium. An intensive



FIG. 1. *G* mode range Raman spectra of pristine, intermediately, and fully doped SWCNTs with a laser excitation of $\lambda = 488$ nm. Upon intermediate doping, the *G*⁻ peak rapidly disappears and the *G*⁺ peak shows an upshift of 10 cm⁻¹. For full doping, the *G*⁺ peak significantly downshifts and it has a Breit-Wigner-Fano line shape (a fit is shown) [49]. The dashed curve shows how the *G*⁺ mode shifts upon doping according to Ref. [47] (the arrow points to increasing doping).

and broad background due to the Ni:Y catalyst particles is observed for the pristine sample. The *g* factor of this signal $(g_{\rm Ni^{2+}} \approx 2.2)$ allowed us to identify it as being due to the Ni²⁺ ion with an intensity compatible with the expected Ni amount in the sample [27]. It was shown [50] that the so-called Tomonaga-Luttinger liquid correlated state broadens the ESR signal of itinerant electrons significantly (beyond 1 Tesla), which makes this signal, together with the small DOS of the undoped SWCNTs, unobservable.

Upon doping, a narrower signal with an ESR linewidth of $\Delta B_{pp} = 2.2(1)$ mT emerges at g = 2.004(2) with an asymmetric line shape. This line shape is known as a Dysonian curve [51] and it can be fitted with a mixture of absorption and dispersion Lorentzian derivative lines [52]. The microwave phase of the mixing is $37(5)^{\circ}$ close to the ideal 45° , which is expected when electrons with a low carrier mobility are embedded in a metal [53]. It is important to note that observation of a Dysonian signal alone is insufficient to identify it as emerging due to conduction electrons. In fact, any spin species (even localized paramagnetic spins or nuclei) that are embedded in a metal, give rise to such a signal [53,54]. The present study confirms this, as the signal due to Ni²⁺ ions is *also* asymmetric in the doped sample (see Fig. 2).



FIG. 2. ESR spectra of pristine and saturated K-doped SWCNT samples at T = 300 K. Note the broad background signal due to the catalyst particles that is present already in the undoped sample and the narrow line that emerges upon doping. The deconvolution of the background and itinerant electron signal is shown for the doped sample as dashed curves.

We also studied the intensity of the ESR signal as a function of the microwave power up to 200 mW irradiation and a cavity quality factor of 3000. We did not observe any saturation effects, which confirms that the narrow component is homogeneously broadened [55]. This provides further proof that this signal originates from the itinerant electrons. The characteristics of the two ESR lines, the broad background due to Ni²⁺ and the narrower CESR component, show that the corresponding two spin systems are electronically decoupled. Were the two kinds of spins coupled, one could not observe two separate ESR lines and a common resonance, which is dominated by the larger spin-susceptibility species, would be observed.

Simultaneously, the overall ESR signal intensity drops significantly due to the limited microwave penetration into the sample and due to a decrease in the cavity quality factor when the sample becomes more metallic. The narrower signal can be identified as being present due to the conduction electrons that are induced upon the charge transfer from the K to the SWCNTs. Several facts support this identification: the Pauli-like temperature dependence of the signal intensity as is discussed below; the linewidth matches well with that in K-doped graphite powder, 2.2(1) mT, and follows a similar temperature dependence [8]. The presence of doped graphite powder can be excluded as the source of this signal as the graphite quantity in the pristine SWCNT samples is too small in the pristine SWCNT samples [27]. Similarly, the



FIG. 3. Temperature dependence of the ESR intensity, linewidth, and sample resistivity for the 100–300 K range. The ESR linewidth data for K-intercalated graphite (KC_8) from Ref. [60] is shown as a solid curve for comparison. The resistivity for the undoped sample is also shown for comparison in (c).

presence of metallic K clusters can be excluded as these have a characteristic ~ 8 mT broad CESR linewidth [56], which is not observed in our data. We note that the confirmation of the homogeneity of the ESR signal would be possible using the pulsed electron paramagnetic resonance method [57,58]. However, this technique is limited to spin systems with smaller homogeneous linewidth (typically 0.1–0.5 mT).

In Fig. 3, we show the temperature dependence of the ESR intensity and the linewidth of the ESR signal assigned to the conduction electrons. The temperature-dependent sample resistivity is also shown. The data are not shown below 100 K due to reasons discussed below. The ESR intensity shows a slight decrease with decreasing temperature (down to 100 K), which proves that this signal indeed originates from the itinerant electrons. Were this signal coming from localized spins, its intensity would *increase* by a factor 3 when going from 300 to 100 K. The slight decrease in the ESR intensity of itinerant electrons occurs due to a change in the microwave penetration into the sample and a change in the microwave cavity quality factor. A similar slight intensity drop was observed for metallic boron-doped diamond [59], which was measured under identical conditions.

The ESR linewidth data in Fig. 3(b) agrees well for K-doped SWCNTs and graphite, which also proves that the above identification is valid. This agreement also shows that the apparent difference in the structure of the two materials does

not affect the ESR linewidth: for both materials ΔB_{pp} is dominated by spin scattering due to the K ions, which was explained for K-doped graphite [60] in the framework of the Elliott-Yafet theory of spin relaxation in metals [61,62]. It is known from the study of alkali-doped fullerides (A_3C_{60} , A =K and Rb) that, for the heavier alkali elements (K and Rb), the ESR linewidth scales with the atomic spin-orbit coupling of the nuclei [63]. However, a characteristic difference is expected for Li-intercalated SWCNT and graphite as therein Li is expected to give a negligible contribution to the spin scattering.

Upon doping, the sample resistivity drops by about a factor 10 at room temperature and its temperature dependence changes character from semiconducting to metallic behavior as shown in Fig. 3(c). These observations agree with previous studies [32,64] and prove that doping makes our powder samples metallic.

Our CESR data below 100 K do not follow the trends described above, due the presence of paramagnetic impurities in our system. Similarly to the case of K_3C_{60} [65], the temperature dependence of the ESR measurables approach the behavior of paramagnetic impurities. This indicates that at these temperatures the so-called *bottleneck regime* is realized, i.e., a strong coupling is present between the paramagnetic and metallic spin systems.

In the following, we discuss the *absolute* value of the static spin susceptibility, χ_0 , and DOS in K-doped SWCNTs. Due to its selection rules, ESR is selective to magnetism that originates from a spin quantum number, i.e., due to the Curie or Pauli susceptibility and is insensitive, e.g., to the Van Vleck or Landau susceptibilities [17]. For this reason, the ESR signal intensity is often mentioned to be a direct measure of the *spin susceptibility*. To obtain absolute values of χ_0 , a calibration of the ESR signal is required as it is detailed in Ref. [59]. In brief, the ESR signal of a well-known paramagnetic intensity standard (CuSO₄ · 5H₂O in our case) is measured that allows one to relate the ESR signal intensity to an actual spin susceptibility. In principle, it allows one to determine χ_0 for any samples.

For the present measurements, an intermediate calibration step is required as the K doping induces a change in the sample conductivity and thus the penetration of microwaves is also affected. The presence of this effect is clear from a signal intensity drop of about a factor 6(1) of the Ni²⁺ ions. To take this effect into account, the measured signal intensity of the K-doped SWCNTs is scaled back with the same factor. From our two-step calibration, we obtain a $\chi_0 = 4.3(9) \times 10^{-6}$ emu/mol for the saturation-doped sample and $\chi_0 = 1.2(3) \times 10^{-6}$ emu/mol for the intermediate-doped sample. The sizable errors of these values arise from the somewhat uncertain amount of SWCNTs in the sample. The DOS of the saturation-doped sample is about seven times larger than that found using electrochemical doping on SWCNT buckypapers in Ref. [48]. This difference is either due to the more efficient doping with the present method or due to the limited microwave penetration into the more bulky buckypapers.

The measured χ_0 static spin susceptibility is related to the DOS through the Pauli susceptibility:

$$\chi_0 = \mu_0 \frac{g^2}{4} \mu_{\rm B}^2 \frac{\rm DOS}{V_{\rm c}},\tag{1}$$



FIG. 4. Density of states as a function of chemical potential. The shady region indicates the experimentally determined DOS including error. Curves depict the DOS in graphene (red), in SWCNTs with the tight-binding approximation (TBA) at T = 0 K (green), and TBA with room-temperature (~26 meV) quasiparticle broadening (blue). The apparent shifting of the latter curve is a mathematical consequence of the convolution of the steplike DOS with the Lorentzian function.

where μ_0 is the vacuum permeability, μ_B is the Bohr magneton, and V_c is the volume of the unit cell [14].

To test the validity of the experimentally determined DOS, we compare it with calculations that were performed on an ensemble of SWCNT as described above. Figure 4 shows a comparison between the experimental DOS result and theoretical calculations as a function of the chemical potential, i.e., the energy separation from the Dirac point. The theoretical data is shown with zero and a finite 300 K (26 meV) broadening parameter. For comparison, the DOS for graphene in the vicinity of the Dirac point is also shown according to Ref. [4]: DOS(E) = $A_c/\pi \times |E|/(\hbar v_F)^2$, where $v_{\rm F} = 1.07 \times 10^6$ m/s is the corresponding Fermi velocity [66] and $A_c = 5.24 \text{ Å}^2/\text{unit cell}$ is the area of the first Brillouin zone (BZ). The gray bar in Fig. 4 shows the value of the experimental DOS, which allows one to deduce the chemical potential shift due to doping. The integration of a given DOS(E) function yields the charge transfer. From this, we obtain that our experimental DOS corresponds to a stoichiometry of $K : C = 1 : (7 \pm 1)$ for the saturation-doped sample. Remarkably, the calculated K to C ratio is close to that found in alkali intercalated graphite $(KC_8 [8])$ and in vapor-phase doped SWCNTs using in situ electron energyloss spectroscopy [67]. Within the limitations posed by the error bar, the experimental and theoretically deduced DOS data are in accordance. This finding means that the system under study does not show strong correlations. In view of the underlying one-dimensional character of the SWCNTs, this observation might sound surprising. However, several previous studies identified the intercalation-induced transition from the Tomonaga-Luttinger liquid to a three-dimensional Fermi-liquid phase [13,27,67,68].

An ensemble of SWCNTs contains a large number of tubes with chiralities that follow a Gaussian diameter distribution





FIG. 5. Reciprocal space distribution of the cutting lines calculated for a typical nanotube ensemble for (a) the first BZ and (b) in the vicinity of the **K** point. The color map from blue to red illustrates the coverage of the possible electronic states. The equienergetic contour line shown in white corresponds to KC₇ saturation doping ($E_{\rm F} \approx 1.73$ eV). Note the C_3 symmetry around the **K** point.

[24,26,38,39,41,44]. One expects that the eventual differences in the SWCNT geometries are smeared out for this ensemble, or even the one-dimensional characters are less pronounced and it is possible to approach graphene, the mother compound of the SWCNTs.

To test this suggestion, we performed calculations investigating to what extent the BZ of graphene is mapped out by a carbon nanotube ensemble. In the zone-folding scheme, the one-dimensional representations of the quantized momentum-space directions of carbon nanotubes [69], i.e., the cutting lines, display the electronic states of a given (n,m)chirality. In Fig. 5, we depict the reciprocal space coverage of a carbon nanotube ensemble in the proximity of the **K** point as the sum of the probability amplitudes of each of the cutting lines of all relevant chiralities. The projection illustrates that *all* the electronic states of graphene are almost homogeneously represented by the carbon nanotube ensemble. The high-symmetry **K** point (as a result of the crossing of the metallic cutting lines) is slightly overrepresented but the coverage at chemical shifts close to our doping (K : C = 1 : 7) barely oscillates around its mean value [70]. Therefore, this illustration proves directly that at high doping levels the SWCNT ensemble behaves as the model system of doped or gate-biased graphene. This provides an additional link between graphene and carbon nanotubes: for an ensemble of SWCNTs the bulk properties (spin and thermal properties) mimic those in graphene and related compounds. In turn, such physical properties of graphene could be studied using carbon nanotube ensembles, in particular as a function of charge doping.

In conclusion, we found that using liquid ammonia doping, the KC_7 saturation potassium doping can be achieved in large quantities of SWCNT ensembles. We demonstrated that ESR is applicable to determine the electronic density of states in alkali-doped SWCNTs, and we confirmed the absence of PHYSICAL REVIEW B 96, 075133 (2017)

strong correlation effects, and that the material behaves as a three-dimensional Fermi liquid. By comparing the reciprocal space of a SWCNT ensemble and biased graphene, we illustrated that potassium-doped SWCNTs provide a tunable model system for graphene.

ACKNOWLEDGMENTS

This work was supported by the Hungarian National Research, Development and Innovation Office (NKFIH) Grant No. K119442, the European Research Council Starting Grant No. ERC-259374-Sylo, and the Swiss National Science Foundation (Grant No. 200021144419).

P.Sz. and B.G.M. contributed equally to this work.

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